

SN Series

SN Sub-Nanosecond Lasers

DPSS, TEM₀₀, Pulse Picked Lasers

Photonics Industries' SN Series sub-nanosecond lasers redefine precision and power in a compact, all-in-one design. With industry-leading high pulse energies and adjustable pulse widths from 5 nanoseconds to an ultra-fast 500 picoseconds, these lasers deliver unparalleled performance for your most demanding applications.

Unlock the potential of the SN Series in diverse applications, from advanced micro processing to cutting-edge scientific innovations like airborne laser ranging (LIDAR). Achieve faster, more accurate results with high-energy pulses tailored to your needs. Elevate your processes with the SN Series—where performance meets possibility.



APPLICATIONS

- Laser Scribing and Texturing
- Laser-Induced Fluorescence and Imaging (LIF)
- PCB & Polymer Cutting & Drilling
- Glass Cutting and Shaping
- Time-Resolved Spectroscopy and Diagnostics
- High-Precision Marking
- Resistor Trimming
- Medical Micro structuring

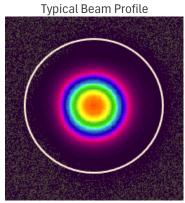
FEATURES

- Up to ~1.5mJ Pulse Energy at 100kHz
- True TEM₀₀ Output
- Short Pulse Widths
- Air-cooled with Radiator Cooled Option
- Robust & Compact Form Factor
- Dynamic Pulse Energy Control PEC
- Power Monitoring and Self-Calibration

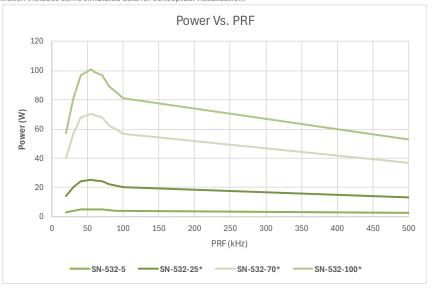


Specifications – SN Series							
	SN-532-5	SN-532-25*	SN-532-70*	SN-532-100*			
Wavelength		532	nm				
Max Average Power ¹	5W	25W	70W	100W			
Max Pulse Energy @ 100kHz	~50uJ ~250µJ ~700µJ ~1mJ						
Pulse Width ³		100ps	to 5ns				
Pulse repetition rate ⁴	Single shot to 2MHz						
Pulse-to-pulse stability ⁵		<2%	rms				
Long-term power stability ²		≤1%	rms				
Beam spatial mode & M ²		TEM ₀₀ - I	M ² <1.2				
Beam divergence (nominal)		<2 m	nrad				
Beam bore sight accuracy	≤ 1 mm lateral	(to specified exit location), ≤	5 mrad angular (to specifie	ed exit direction)			
Beam roundness		>9(0%				
Beam pointing stability		<20	ırad				
Polarization ratio		Horizonta	l; >100:1				
		Operational Specification	ons and Characteristics				
Interface		RS232, Ethernet, Software 0	GUI, External TTL Triggering				
Warm-up time		< 5 minutes from standby, <	10 minutes from cold start				
Electrical requirement		100-24	0 V AC				
Line frequency		50-6	0 Hz				
Power consumption ⁶	~200W	~500W	~900W	~1300W			
Dimensions ⁷	18 x 5 x 8.90in	16 x 8.5 x 4.5 in.	20 x 8.5 x 4.5 in.	20 x 10 x 4.5 in.			
Weight	35lbs [~15.8kg]	~38lbs	~47lbs	~57lbs			
		Environmental	Requirements				
Ambient temperature ²		Ambient 15°C to 30°C (59°I	F to 86°F) Operating Range				
Ambient temperature		Relative humidity 0% to 80	0% max, non-condensing				
Storage conditions		-10°C to 40°C; sea	level to 12000 m				
Sicrage conditions		0% to 80% relative Hun	nidity, non-condensing				
Cooling system	Air-Cooled		Water-Cooled				
104		1 200 1 8 1					

[1.] Standard power optimization is at 1 MHz. Output power is specifiable at different pulse repetition rates. Pulse energy varies depending on the repetition rate optimization and specified pulse width. > 3 mJ single pulse energy optimization is available. [2.] Measured over 8 hours ± 1°C. [3.] Specifiable pulse width. Pulse energy varies depending on the specified pulse width. [4.] Lower pulse repetition rate operation, down to single shot, achieved by utilizing PSO or POD features. Higher pulse repetition rates are available [5.] Measured at ambient temperature ± 2°C. [6.] Power consumption data does not include an external chiller's power consumption. [7.] SN Series sub-nanosecond lasers are all-inone (AIO) and do not require a separate controller or utility module. All connections for operation and control of the laser can be found on the back panel of the AIO laser. [8.] 60V/20A and 32V/28A two connections between laser head and PSU. *Illustration includes some simulated data for conceptual visualization.



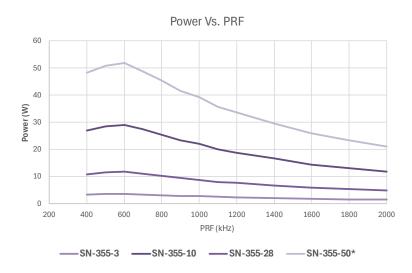
SN-532-5





Specifications – SN Series								
	SN-355-3	SN-355-10*	SN-355-28*	SN-355-50*				
Wavelength		355	nm					
Max Average Power ¹	3W	10W	28W	50W				
Max Pulse Energy @ 100kHz	~30µJ	μ] ~100μ] ~280μ] ~500μ]						
Pulse Width ³		100ps	– 5ns					
Pulse repetition rate ⁴		Single sho	t to 2MHz					
Pulse-to-pulse stability ⁵	<2% rms							
Long-term power stability ²	≤1% rms							
Beam spatial mode & M ²		TEM ₀₀ - M ² < 1.2						
Beam divergence (nominal)		~ 2 m	nrad					
Beam bore sight accuracy	≤ 1 mm lateral	(to specified exit location), ≤	5 mrad angular (to specifie	d exit direction)				
Beam roundness		>90	%					
Beam pointing stability		<25 µ	ırad					
Polarization ratio	Vertica	l; >100:1	Horizonta	l; >100:1				
		Operational Specification	ns and Characteristics					
Interface		RS232, Ethernet, Software C	GUI, External TTL Triggering					
Warm-up time		< 5 minutes from standby, <	10 minutes from cold start					
Electrical requirement		100-24	0 V AC					
Line frequency		50-60) Hz					
Power consumption ⁶	~200W	~500W	~900W	~1300W				
Dimensions ⁷	18 x 5 x 8.90in	16 x 8.5 x 4.5 in.	25.5 x 10) x 4.5in				
Weight	35lbs [~15.8kg]	~38lbs	~71	lbs				
		Environmental	Requirements					
Ambient temperature 2		Ambient 15°C to 30°C (59°F	to 86°F) Operating Range					
Ambient temperature ²		Relative humidity 0% to 80	0% max, non-condensing					
Storage conditions		-10°C to 40°C; sea	level to 12000 m					
Storage conditions		0% to 80% relative Hum	nidity, non-condensing					
Cooling system	Air-Cooled		Water-Cooled					

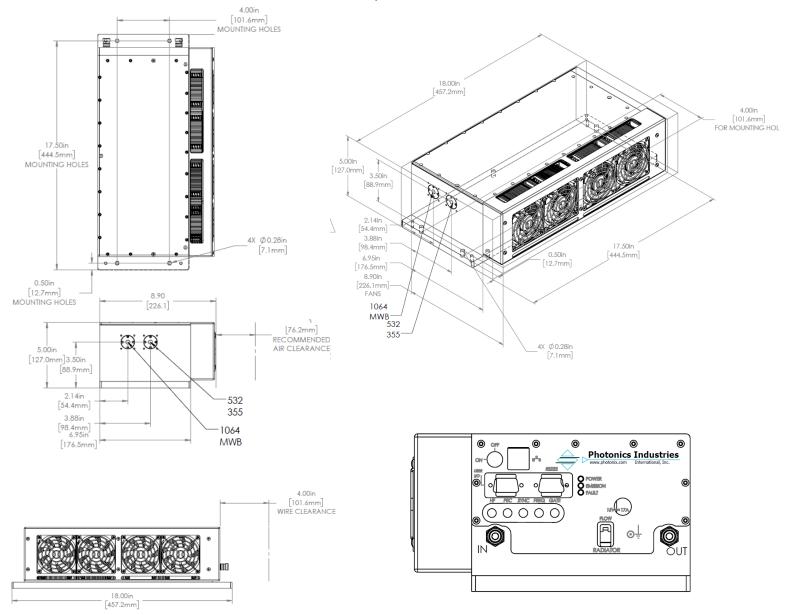
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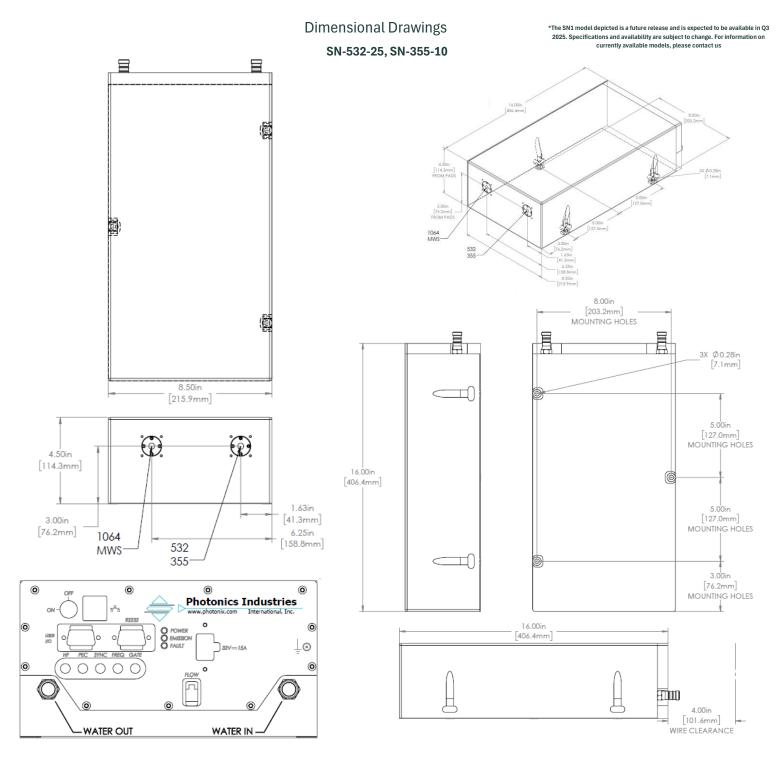
Dimensional Drawings

SN-532-5, SN-355-3



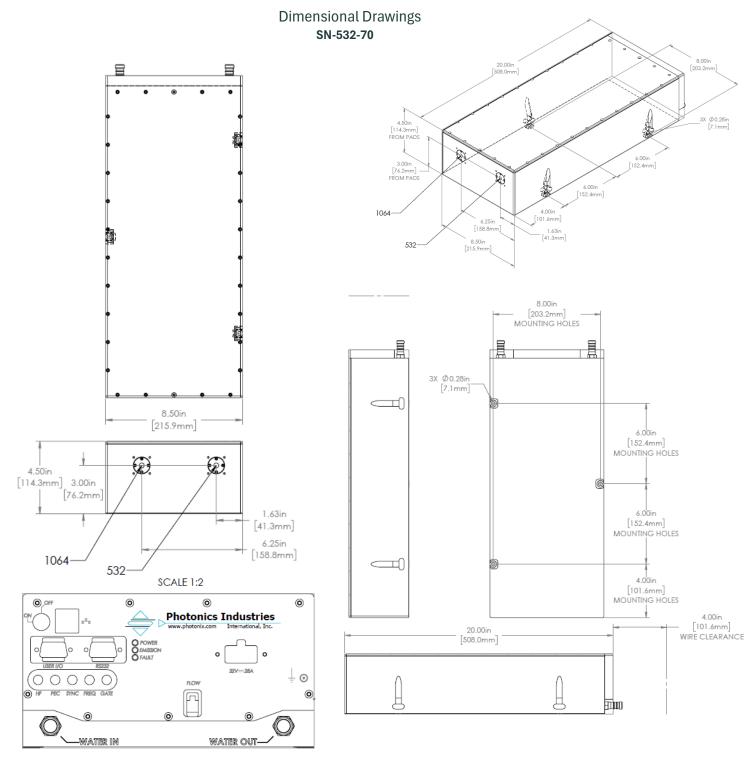
Options:				
Multi-wavelength	Multi-wavelength o	utput, blende	ed or selectable	[MWB], [MWS]
Deep Ultraviolet (DUV)	266nm Waveleng	gth available	upon request	[SN-266]
Rad-cooling™	Rad-cooling™ system instead of air-cooling fans			[RC]
Format	SN-1064/532/355	-	[Power level]	- [xxx]





Options:					
Multi-wavelength	Multi-wavelength outpu	t, bler	nded or selectable		[MWB], [MWS]
Deep Ultraviolet (DUV)	266nm Wavelength a	vailab	le upon request		
					<u> </u>
Format	SN-1064/532/355/266	-	[Power Level]	-	[XXX]

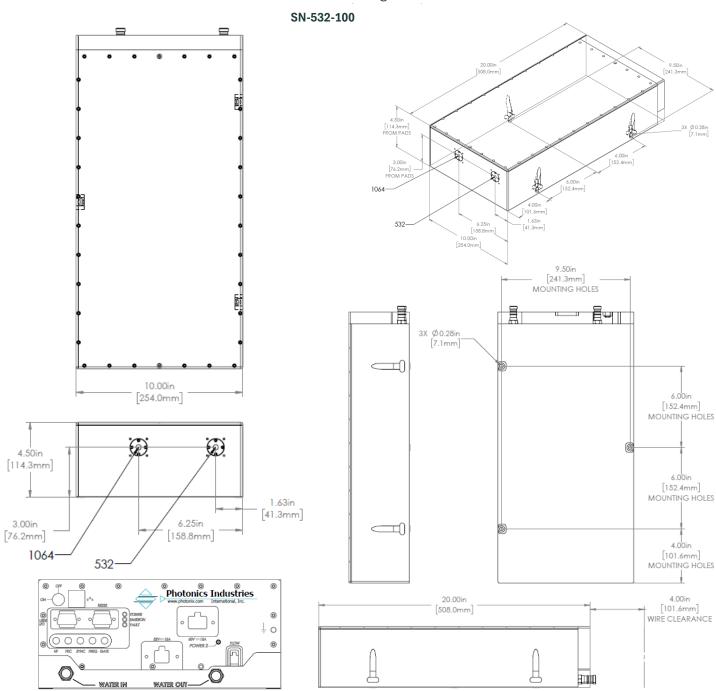




Options:				
Multi-wavelength	Multi-wav	elength	output	[MWB]
				I.



Dimensional Drawings



Options:				
Multi-wavelength	Multi-wavelen	gth outpu	ıt, blended	[MWB]

8.00in [203.2mm]

[203.2mm] MOUNTING HOLES

8.00in

[203.2mm] MOUNTING HOLES

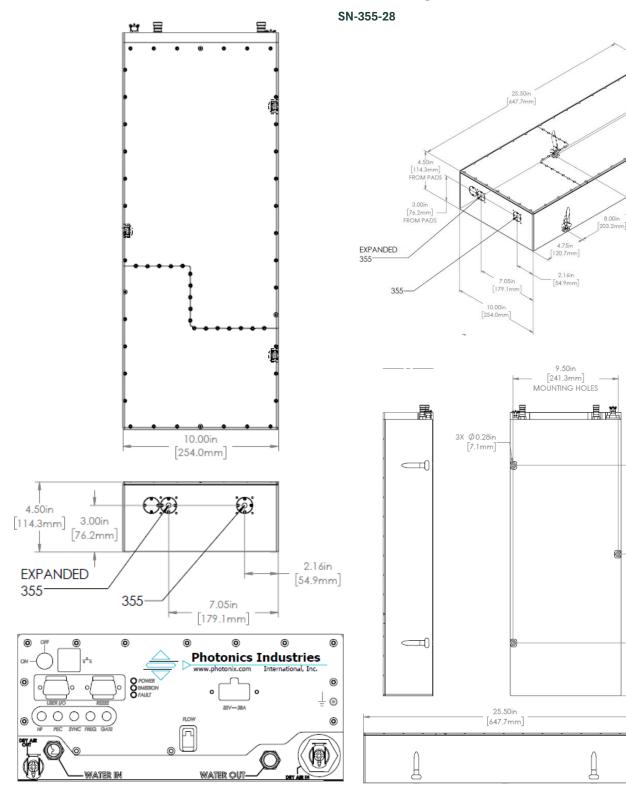
4.75in [120.7mm] MOUNTING HOLES

4.00in

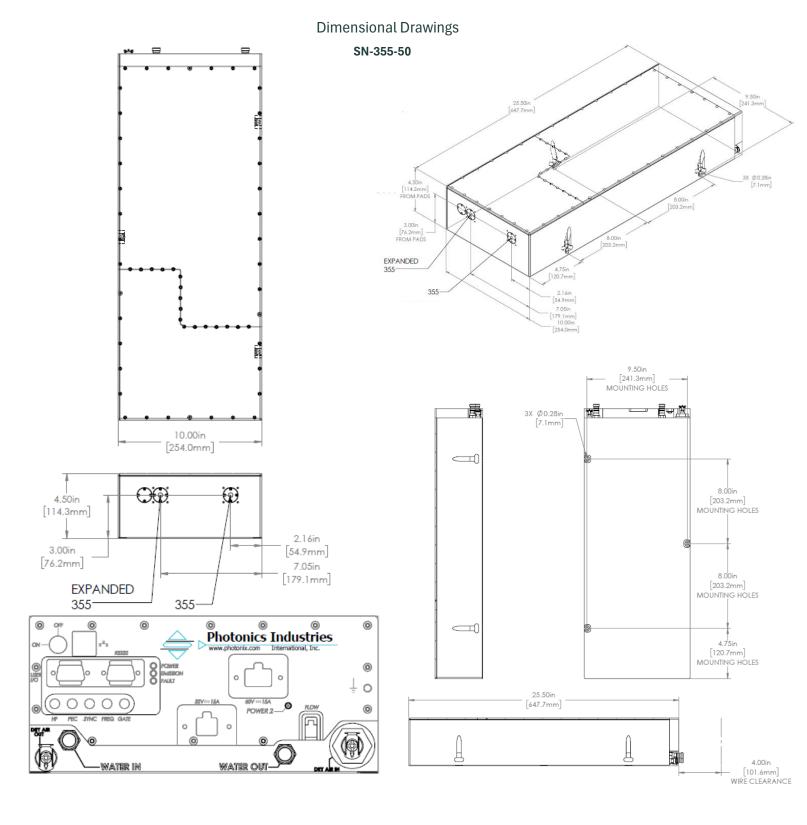
- [101.6mm] WIRE CLEARANCE



Dimensional Drawings









Our ongoing policy is to improve the design and specification of our products. The information provided is non-binding. © 2025 Photonics Industries International, Inc.

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Photonics Industries International Inc. is the pioneer of intracavity harmonic lasers and is at the forefree of developing, manufacturing, and marketing a wide range of nanosecond, sub-nanosecond, picosecond, and femtosecond lasers for the industrial, scientific, defense and medical industries.



